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Attorney Docket No.: DB000575-023

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE JAN 23 MON MALL MOON

Applicant(s): Keeth, et al.

**Examiner:** Not yet assigned  $\bigcirc$ 

Serial No.:

09/934,795

Art Unit: 2816

Filed:

22 August 2001

**Entitled:** 

256 MEG DYNAMIC RANDOM ACCESS MEMORY

## SECOND PRELIMINARY AMENDMENT

Preliminary to the examination of the above-identified application, please amend that application as follows.

## In the claims

Please amend claims 174 and 175 as follows.

174. (Amended) A method of controlling the conduction of a pair of isolation transistors in a sense amplifier responsive to an array/, comprising [the steps of]:

rendering the pair of transistors conductive/with a control signal that is a boosted version of the voltage used by the array;/and

rendering the pair of transistors nonconductive by removing said control signal.

175. (Amended) The method of claffm 174 wherein said step of rendering the pair of transistors conductive includes the step of rendering the transistors conductive with a control signal that is approximately a [Vt] Vth higher than the voltage used by the array.

